



NTH4L060N065SC1

Table 1. THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Max	Unit
- - -			

NTH4L060N065SC1

Table 2. ELECTRICAL CHARACTERISTICS

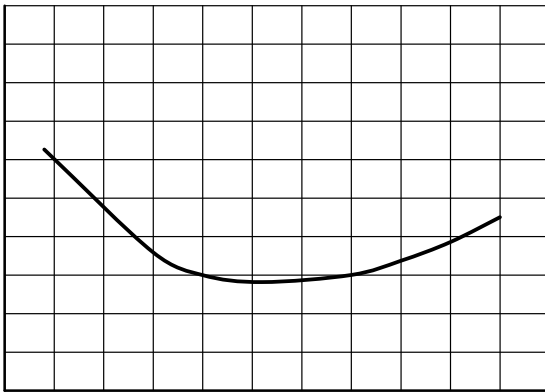
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
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DRAIN-SOURCE DIODE CHARACTERISTICS

		-	-		-	
		μ	-		-	
			-		-	μ

NTH4L060N065SC1

TYPICAL CHARACTERISTICS



NTH4L060N065SC1

TYPICAL CHARACTERISTICS

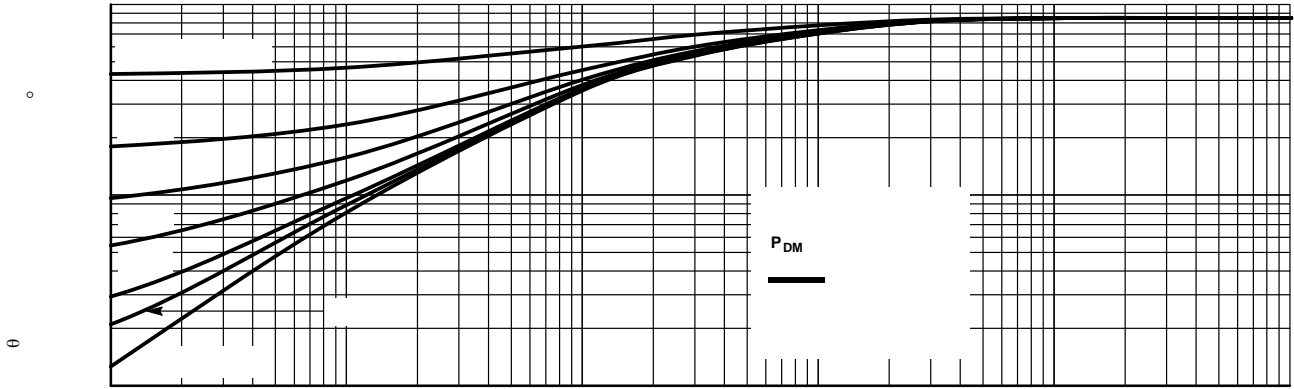


Figure 13. Junction-to-Case Thermal Response

TO-247-4LD
CASE 340CJ
ISSUE A

DATE 16 SEP 2019

A E A B
A2 E1 \emptyset p1
D2

E/2 Q

D D1

\emptyset

L1

b2 A1

b1 (3X) L

1 4

e1 b(4X) c

e 2X

\oplus 0.254 (M) B A (M)

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